



KBU8005 Thru KBU810

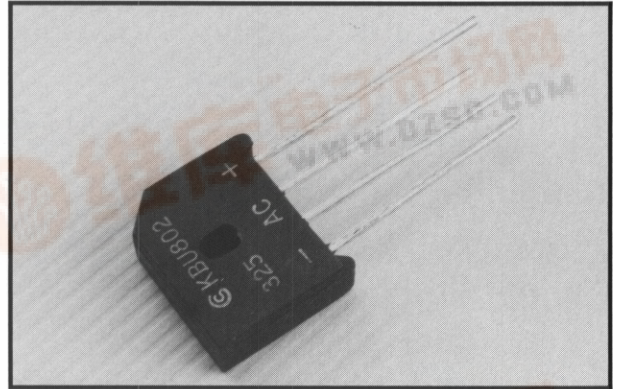
8 AMP SILICON BRIDGE RECTIFIER

FEATURES

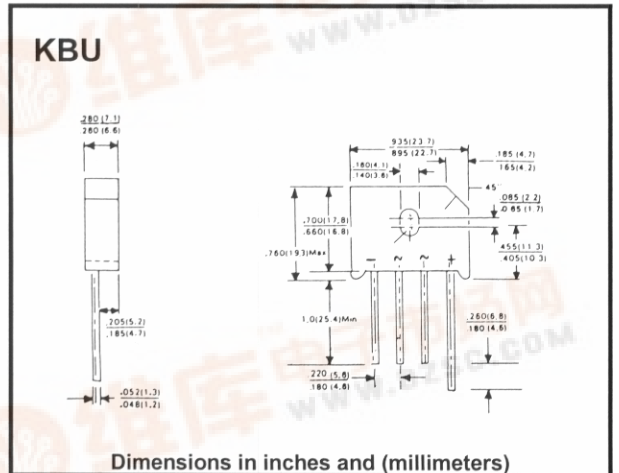
- Rating to 1000V PRV
- Ideal for printed circuit board
- Surge overload rating to 300 Amperes peak
- Reliable low cost construction utilizing molded plastic technique
- UL recognized: File #E106441
- UL recognized 94V-O plastic material

Mechanical Data

- Case: Molded Plastic
- Mounting torque: 5 in. lb. max.
- Mounting position: Any
- Weight: 0.3 ounce, 8.0 grams



Outline Drawing



Maximum Ratings & Characteristics

- Ratings at 25° C ambient temperature unless otherwise specified
- Single phase, half wave, 60Hz, resistive or inductive load
- For capacitive load, derate current by 20%

		KBU 8005	KBU 801	KBU 802	KBU 804	KBU 806	KBU 808	KBU 810	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	60	100	200	400	600	800	1000	V
Maximum Average Forward Output Current	@ T _J = 100°C @ T _A = 65°C	I (AV) 8.0							A
Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave Superimposed On Rated Load	I _{FSM}	300							A
Maximum DC Forward Voltage Drop per Element At 4.0A DC	V _F	1							V
Maximum DC Reverse Current At Rated DC Blocking Voltage per Element	@ T _A = 25°C @ T _C = 100°C	I _R 10 1							μA mA
Maximum Thermal Resistance (Note)	R _{THJC}	5							°C/W
Operating Temperature Range	T _J	-55 to +125							°C
Storage Temperature Range	T _{STG}	-55 to +150							°C

Note: Thermal resistance junction to case per diode